Triplet pair correlations and nonmonotonic supercurrent decay with Cr thickness in Nb/Cr/Fe/Nb Josephson devices

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Supercurrents carry charge but not spin in the vast majority of superconductors. This is because the charge carriers are Cooper pairs which are formed of electrons with antiparallel spins (singlet pairs). It is now established that if singlet pairs propagate through a superconductor interface with an inhomogeneous ferromagnet, triplet pair correlations form so the supercurrents can acquire a net spin component. Although the spins at sputter-deposited Fe/Cr interfaces can be frustrated due to surface roughness and interdiffusion, an antiferromagnetic spin density wave (SDW) state can still form in Cr close to the interface. Here, we show evidence for triplet pair correlations in Josephson junctions with Cr/Fe and Cr/Fe/Cr barriers. Although the exact mechanism of pair conversion is unknown, we propose a simple model in which a SDW state in Cr and frustrated spins at the Cr/Fe interfaces serve as spin-mixers for generating triplet supercurrents and so provide a potential means to generating large superconducting spin current densities.

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Spin-triplet theory (e.g. [1–4]) and experiments [5–19] which provide evidence of triplet pairing have mainly focused on triplet pair formation at magnetically inhomogeneous superconductor-ferromagnet (S-F) interfaces (so-called "spin-mixer" interfaces). In S-F-S Josephson devices in which both S-F interfaces serve as spin-mixers, Cooper pairs with parallel spins can form, meaning that supercurrents in the F layer can potentially carry spin in addition to charge. Consequently, triplet supercurrents could be used as transmitters of spin in logic circuits without ohmic dissipation, and so a better understanding of the triplet proximity effect and the discovery of different spin-mixers could lead to the development of superconducting spin-electronics as a major research field [4].

The basic picture of how spin-polarized triplet pairs are generated in S-F junctions can be summarized as follows. If the magnetization at the interface is collinear to the magnetization of the F layer, spin-zero triplet pairs are induced [1]. Like singlet pairs, these are short ranged in F materials, but unlike singlet pairs, spin-zero triplets are rotationally variant, and so if the interface magnetization makes an angle to the magnetization of the F layer, spin-polarized triplet pairs form which are long ranged in F. For a review, see Ref. [2].

Spin-triplet theory was initiated [1] more than a decade ago following the report of long-range (\gg 10 nm) superconducting pair correlations in Al/Co [5] and Al/Ni [6] devices in which singlet pairing seemed impossible. Interferometer measurements also demonstrated evidence of long-ranged superconducting pair correlations in Ho [7]. More direct evidence of triplet pairing was obtained in Josephson devices with half-metallic ferromagnetic CrO₂ barriers [8]; the absence of minority spin states at the Fermi energy of CrO₂ ruled out singlet pairing and so implied the supercurrents were not only carried by triplet pairs [20] but that the supercurrents were 100% spin-polarized. More recently, engineered spin-mixers have been demonstrated in Josephson devices with F'-F-F'-type barriers [9–11,13,14], as theoretically proposed in Ref. [3]. Here the F' and F layers are noncollinearly aligned and so the F'-F interfaces serve as spin-mixers, while the thickness of the F layer should be larger than the singlet pair coherence length (1–3 nm [21–24]). Experimental device barriers for generating triplet supercurrents are very complicated and include, for example, Cu/Ni/Cu/Co/Ru/Co/Cu/Ni/Cu [9,13], Co/Ho/Co [10], and Ni/CrO₂/Ni [14]. Evidence of triplet pairing has also been reported by Leksin *et al.* [17] and Zdravkov *et al.* [25] from critical temperature measurements of S-F'-F-type structures, as theoretically proposed in Ref. [26].

Identifying and investigating alternative spin-mixers for generating triplet pair correlations is important since existing structures often containing many interfaces and materials with poorly matched resistivities. These factors limit device performance by reducing pair transmission and the spin current density which can be carried by the triplet state. Here, we report results using Cr, a spin-density wave (SDW) antiferromagnet (AFM), as a spin-mixer in Josephson junctions with Cr/Fe and Cr/Fe/Cr barriers.

In order to investigate the magnetic properties of our Fe/Cr interfaces, we performed current-in-plane (CIP) magnetoresistance (MR) measurements on Nb/Cr/(Fe/Cr)x20 films and magnetization versus in-plane field hysteresis loops (M-H loops). The films were grown by dc magnetron sputtering in Ar at 1.5 Pa onto unheated single-crystal silicon (001) substrates with a 250-nm-thick oxide layer on the surface. Before film growth, the system was cooled via a liquid nitrogen jacket in order to lower the system's base pressure to below 10^{-8} Pa. Targets were presputtered until a constant voltage was achieved. Substrates rested on a circular sample table, which could be rotated below the stationary sputtering targets. Film thicknesses were controlled by the speed of rotation and target power with a resolution better than 1 nm. Growth rates were precalibrated by growing films onto patterned substrates and by measuring the height of step edges with an atomic force microscope.

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FIG. 1. (Color online) Magnetic properties of a Nb/Cr/ $(Fe/Cr)_{\times 20}$ /Nb film (sketched in the inset). (a) CIP MR data at different temperatures in which the field is applied parallel to the long axis of the sample and perpendicular to the current direction. (b) Corresponding (normalized) *M*-*H* loops.

Figure 1(a) shows CIP MR data from a Nb/Cr/(Fe/Cr)_{×20} film. The field was applied parallel to the interfaces. For all temperatures, the resistance (*R*) of the film is largest near zero field, but decreases as the field increases, implying a change in the magnetization alignment of neighboring Fe layers from (approximately) antiparallel in zero field to parallel in high field. However, the low-temperature MR data shows no evidence of *R* reaching a saturation minimum value, implying that a fully parallel state is not obtained in the field range investigated. This behavior contrasts with the *M*-*H* loop data shown in Fig. 1(b) where, for all temperatures, the saturation moment (M_s) is achieved below 1 T.

A high-field saturation of MR in Fe/Cr multilayers can be explained if we assume that the spins at the Fe/Cr interfaces are frustrated [27]. In Fe/Cr films, the following magnetic interactions take place: ferromagnetic Fe-Fe and AFM Cr-Cr interactions within Fe or Cr layers, and AFM Fe-Cr interactions at the interface. For atomically flat and pristine Fe/Cr interfaces, the spins point in plane, meaning all three interactions coexist, while at more realistic Fe/Cr interfaces, roughness and interdiffusion complicate the interactions by introducing frustration. At lower temperatures, the anisotropy associated with the frustrated interface must increase, and this necessarily means that larger fields are required to align the interface spins to the applied field. Hence, increasingly large fields are required for R to decrease to a minimum value at lower temperatures. The M-H loops [Fig. 1(b)] show a much lower saturation field than implied from the MR data, meaning that the net moment of the interface is small relative to the total moment of the Fe layers.

To explore the interaction of superconductivity with Fe/Cr, we first fabricated Nb/Fe/Cr/Nb Josephson devices. The devices were fabricated from films by defining 4- μ m-wide and 30- μ m-long tracks by optical lithography and Ar-ion etching. Patterned films were then transferred to a focused ion beam microscope where current perpendicular-to-plane devices were created (see Ref. [28] for further details). Device measurements were performed in a μ -metal shielded dipstick probe in a liquid helium dewar. The current-voltage (*I-V*) curves were measured in a four-point current-biased



FIG. 2. (Color online) $I_C R_N$ versus d_{Cr} for Nb/Cr/Fe (1.8nm)/Nb junctions at 4.2 K. The data at $d_{Cr} = 0$ is taken from Ref. [23]. The solid curve is a fit to Eq. (1). Insets: (a) AR_N versus d_{Cr} and (b) and (c) magnetic field H for different Cr thicknesses (labeled).

configuration using a lock-in amplifier setup. The junction critical current (I_C) is defined as the current corresponding to the peak in the differential resistance. The normal state resistance (R_N) is determined at high bias where the slope of I-V is constant. Because the junction areas vary between devices, we calculate the characteristic voltage $I_C R_N$ and use this parameter to compare different devices.

In Fig. 2, we have plotted the dependence of the $I_C R_N$ of these junctions on Cr layer thickness (d_{Cr}). The Fe layer thickness was constant for all devices (1.8 nm). A Josephson effect was confirmed by measuring the dependence of I_C on an in-plane magnetic field H (Fraunhofer patterns); examples are shown in Figs. 2(b) and 2(c). The hysteresis in $I_C(H)$ is due to magnetic flux [29] from the Fe layer and is independent of d_{Cr} .

The data in Fig. 2 shows that, although $I_C R_N$ decays as a function of d_{Cr} , it is not monotonic as expected for a simple S/AFM/S device. If such behavior was due to systematic changes in R_N , the resistance-area product (AR_N) of the devices should match the trend of $I_C R_N$ versus d_{Cr} . However, as shown in Fig. 2(a) AR_N approximately depends linearly on d_{Cr} without any correlation with the $I_C R_N$ versus d_{Cr} data. We also note that the critical current density (I_C per unit area) has the same behavior as $I_C R_N$ versus d_{Cr} (data not shown). The nonmonotonic behavior of $I_C R_N$ must, therefore, be due to an interaction of the Cooper pairs with AFM Cr.

A nonmonotonic Cr thickness dependence of $I_C R_N$ is only expected if the integrated exchange field in Cr is nonzero over the pair coherence length such as in S-F-S Josephson devices [30]. If the Cr is a simple AFM such that spins between adjacent atomic planes are antiparallel, then such a modulation is not possible. However, Cr is a SDW AFM and Josephson devices with Cr show an anomalously short coherence length of $\xi_{Cr} \sim 4$ nm [31,32], which is likely due to an interaction between pairs and a random incommensurate SDW state.

Based on the previous studies of Josephson devices with Cr, we argue here that the most probable explanation for the

nonmonotonic behavior of $I_C R_N$ in d_{Cr} is that the electron pairs interact with a SDW state in Cr, which is exchange coupled to the Fe. To our knowledge, this situation has not been microscopically modeled in the context of the superconductor proximity effect. Nevertheless, we are able to capture the form of the experimental data using a simple phenomenological model in which we assume that, due to the exchange coupling of the Cr with the Fe, the SDW can be described as a coherent modulation of the local magnetic moment with a fixed wavelength λ (in Cr thin films, λ is extended and can be longer than 4 nm [33]). Within the general framework of S-F-S junctions, the net supercurrent across the barrier will be dependent on the net phase difference acquired by the electron pairs as a result of the integrated exchange field in the barrier. Since the Fe is a constant thickness, it induces a constant phase difference φ , and during the passage through the Cr, the pairs will acquire an additional phase shift induced by the effective exchange field associated with the SDW, which we define as $(B\lambda/2\pi)\sin(\alpha + 2\pi x/\lambda)$. Here, α is the phase of the SDW at the Fe/Cr interface ($d_{Cr} = 0$), and since on average the Fe/Cr interface is antiparallel, we set $\alpha = -\pi/2$. It can be shown that the characteristic voltage is given by adding the integral of this phase shift with respect to x to φ

$$I_C R_N = A \cos \left[\phi + B \cos \left(\alpha + \frac{2\pi d_{\rm Cr}}{\lambda} \right) \right] \exp \left(\frac{-d_{\rm Cr}}{\xi_{\rm Cr}} \right).$$
(1)

The final exponential stems from averaging over diffusive trajectories (e.g. [2]).

The values of φ and *A* can be estimated from a plot of $I_C R_N$ versus d_{Fe} for Nb/Fe/Nb junctions. In Ref. [23], we report such data (also shown in Fig. 3), and for $d_{\text{Fe}} \sim 1.8$ nm, $I_C R_N$ is midway between a zero and a peak, and so we set $\varphi = 7\pi/4$. We assume a singlet coherence length in Cr of $\xi_{\text{Cr}} = 4$ nm, which closely matches the decay envelope of the data in Fig. 2. This value is also consistent with values obtained in Refs. [31] and [32] for Cr thicknesses where a SDW state is assumed to form. Using the only adjustable parameter *B*, which corresponds to the relative exchange field of the SDW, a fit using the above equation agrees well with the experimental data.

It is important to emphasize that, in order to describe the complex behavior of I_C on d_{Cr} , our model assumes an effective interaction between the superconducting pairs induced in the Cr and the SDW [proportional to *B* in Eq. (1)]. This interaction breaks the time-reversal symmetry of the Cooper pairs and therefore necessarily implies the presence of triplet pair correlations as in conventional S-F-S junctions [1]. Furthermore, the frustrated spins at the Fe/Cr interfaces (Fig. 1) should theoretically serve as additional spin-mixers.

If spin-zero triplet pair correlations are present in devices with Cr/Fe barriers, then in a device with a symmetrical barrier such as Cr/Fe/Cr, it is our hypothesis that spin-one triplets may also form (this is consistent with Ref. [3]). To test this hypothesis, we fabricated Josephson devices with Cr/Fe/Cr barriers in which d_{Fe} was systematically varied. In Fig. 3(a), we have plotted I_CR_N for a series of junctions as a function of d_{Fe} . Each Cr layer has a thickness of 2.5 nm; this thickness was chosen since, at this thickness, we obtained the maximum value of I_CR_N in Fig. 2.



FIG. 3. (Color online) (a) $I_C R_N$ versus d_{Fe} at 4.2 K for different barrier configurations: Cr(2.5)/Fe/Cr(2.5) (•); Fe only (III) with an exponential decay (gray line) assuming a coherence length of 3 nm, taken from Ref. [23]; and Fe(1.35)/Cr(2.5)/Fe(1.35) barriers (\blacktriangle) (estimated from Ref. [34]) with parallel aligned Fe layers (the red curve is a guide to the eye). (b) and (c) Fraunhofer oscillations of I_C with an in-plane magnetic field for two devices with different Fe layer thicknesses (labeled); hysteresis in $I_C(H)$ depends on field treatment, junction dimensions, and d_{Fe} .

Although there is a lot of scatter in $I_C R_N$ versus d_{Fe} , the pair coherence length in Fe for some devices is much longer than the known coherence length for singlet pairs in Fe of only 1 nm [23]. This is clear if we compare the Nb/Cr/Fe/Cr/Nb data to values of $I_C R_N$ obtained from Nb/Fe/Cr/Fe/Nb devices [34] which also include the additional decay due to the presence of Cr and Fe/Cr interfaces [reproduced in Fig. 3(a)]. For all Fe layer thicknesses investigated, the magnitude of $I_C R_N$ of the Nb/Cr/Fe/Cr/Nb devices is significantly larger than values obtained for Nb/Fe/Cr/Fe/Nb devices. For comparison, we also plot $I_C R_N$ data obtained Nb/Fe/Nb devices [23], which do not include Cr or Fe/Cr interfaces.

The fact that we observe enhanced supercurrents in Nb/Cr/Fe/Cr/Nb is compelling evidence for the generation of spin-triplet correlations in Cr/Fe/Cr barriers. The scatter in I_CR_N versus d_{Fe} is interesting as it may indicate that the generation of spin-one triplets is dependent on differences between the Cr layers on either side of the Fe layer. In Ref. [3], it is theoretically shown that the generation of spin-one triplets

in devices with F'-F-F' barriers is strongly dependent on the symmetry between the two F' layers; while the F'-F interfaces need to be noncollinear, the two F' layers should be collinear in order to maximize the generation of triplet pairs. In our Cr/Fe/Cr devices, the orientation of the spins in one Cr layer are unlikely to match the orientation of the spins in the second Cr layer, and so the efficiency of triplet pair generation is likely to vary between devices.

On the basis of the data in Figs. 1 to 3 and our phenomenological analysis, we suggest that spin-zero and spin-one triplets are generated due to the SDW state in Cr and frustration at the Fe/Cr interfaces. This necessarily implies a novel method of triplet pair generation. Spectroscopic

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measurements, which can probe the local density of states in Fe/Cr in the superconducting state, should now be performed in order to understand better the nature of the triplet state [35]. Scanning tunneling spectroscopy on S/half-metallic junctions has revealed features such as zero-bias conductance peaks [36,37] which are associated with an odd frequency spin-triplet state, while Andreev spectroscopy on similar structures has shown evidence for equal-spin Andreev reflection [38].

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